



IXFB170N30P Information

www.helsener.com

For Reference Only

Part Number IXFB170N30P

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH TO-264 **Package** TO-264-3, TO-264AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXFB170N30P Specifications

Manufacturer Part Number	IXFB170N30P
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-264-3, TO-264AA
Series	HiPerFET?, PolarP2?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	300V
Current - Continuous Drain (Id) @ 25°C	170A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	258nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	20000pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	1250W (Tc)
Rds On (Max) @ Id, Vgs	18 mOhm @ 85A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PLUS264?
Package / Case	TO-264-3, TO-264AA
	Report errors?

IXFB170N30P Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFB170N30P Payment Methods



















IXFB170N30P Shipping Methods













If you have any question about IXFB170N30P, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com